Dual supply translating transceiver; auto direction sensing; 3-state

Rev. 4 — 23 January 2013

Product data sheet

1. General description

The NTB0102 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 2-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins ($V_{CC(A)}$ and $V_{CC(B)}$). $V_{CC(A)}$ can be supplied at any voltage between 1.2 V and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.2 V, and 3.6 V and $V_{CC(B)}$ can be supplied at any voltage between 1.65 V and 5.5 V, making the device suitable for translating between any of the low voltage nodes (1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V).

Pins An and OE are referenced to $V_{CC(A)}$ and pins Bn are referenced to $V_{CC(B)}$. A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range:
 - ◆ V_{CC(A)}: 1.2 V to 3.6 V and V_{CC(B)}: 1.65 V to 5.5 V
- I_{OFF} circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
 - ◆ HBM JESD22-A114E Class 2 exceeds 2500 V for A port
 - ◆ HBM JESD22-A114E Class 3B exceeds 15000 V for B port
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1500 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C



Ordering information 3.

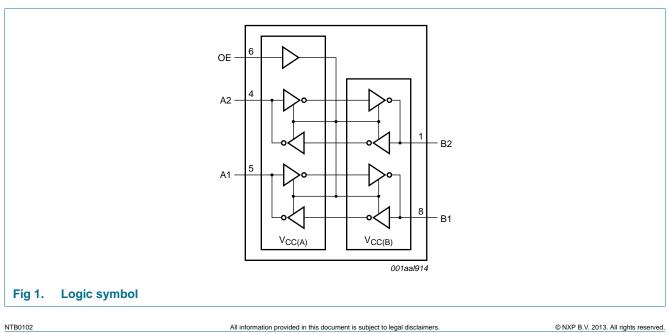
Type number	Package									
	Temperature range	Name	Description	Version						
NTB0102DP	–40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2						
NTB0102GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1						
NTB0102GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm	SOT996-2						
NTB0102GF	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 \times 1 \times 0.5 mm	SOT1089						
NTB0102GU	–40 °C to +125 °C	XQFN10	plastic, extremely thin quad flat package; no leads; 10 terminals; body $1.40 \times 1.80 \times 0.50$ mm	SOT1160-1						

Marking 4.

Table 2. Marking	
Type number	Marking code ^[1]
NTB0102DP	t02
NTB0102GT	t02
NTB0102GD	t02
NTB0102GF	t2
NTB0102GU	t2

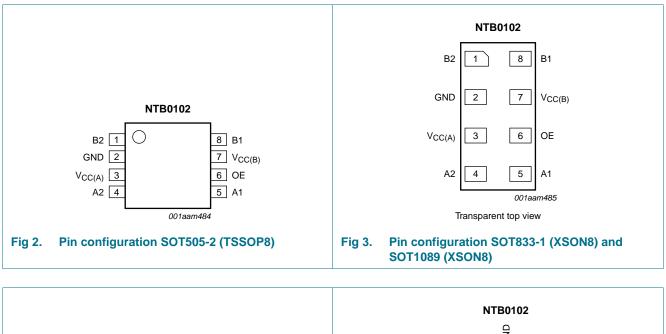
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

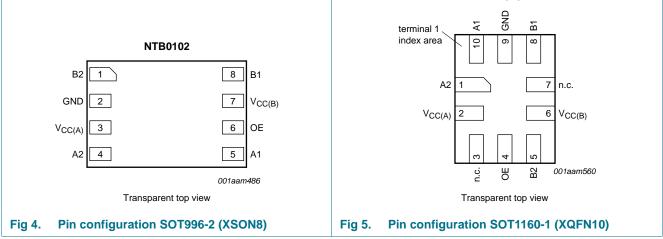
Functional diagram 5.



6. Pinning information

6.1 Pinning





6.2 Pin description

Table 3.	Pin description		
Symbol	Pin	Description	
	SOT505-2, SOT833-1, SOT1089 and SOT996-2	SOT1160-1	_
B2, B1	1, 8	5, 8	data input or output (referenced to $V_{CC(B)}$)
GND	2	9	ground (0 V)
V _{CC(A)}	3	2	supply voltage A
A2, A1	4, 5	1, 10	data input or output (referenced to $V_{CC(A)}$)

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Table 3.	Pin description continued		
Symbol	Pin	Description	
	SOT505-2, SOT833-1, SOT1089 and SOT996-2	SOT1160-1	_
OE	6	4	output enable input (active HIGH; referenced to $V_{CC(A)}$)
V _{CC(B)}	7	6	supply voltage B
n.c.	-	3, 7	not connected

7. Functional description

Table 4.Function table^[1]

Supply voltage		Input	Input/output	
V _{CC(A)} V _{CC(B)}		OE	An	Bn
1.2 V to $V_{CC(B)}$	1.65 V to 5.5 V	L	Z	Z
1.2 V to V _{CC(B)}	1.65 V to 5.5 V	Н	input or output	output or input
GND ^[2]	GND ^[2]	Х	Z	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] When either $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into Power-down mode.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(A)}	supply voltage A		-0.5	+6.5	V
V _{CC(B)}	supply voltage B		-0.5	+6.5	V
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
Vo	output voltage	Active mode	<u>[1][2][3]</u> –0.5	V _{CCO} + 0.5	V
		Power-down or 3-state mode	<u>[1]</u> –0.5	+6.5	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
Ι _{ΟΚ}	output clamping current	V _O < 0 V	-50	-	mA
I _O	output current	$V_{O} = 0 V$ to V_{CCO}	[2] _	±50	mA
I _{CC}	supply current	$I_{CC(A)}$ or $I_{CC(B)}$	-	100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[4] _	250	mW

[1] The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V_{CCO} is the supply voltage associated with the output.

[3] V_{CCO} + 0.5 V should not exceed 6.5 V.

 $\begin{array}{ll} \mbox{[4]} & \mbox{For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K. \\ & \mbox{For XSON8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K. \\ & \mbox{For XQFN10 package: above 128 °C the value of P_{tot} derates linearly with 11.5 mW/K. \\ \end{array}$

9. Recommended operating conditions

Table 6.	Recommended operating condit	ions[1][2]					
Symbol	Parameter	Conditions	Min	Max	Unit		
V _{CC(A)}	supply voltage A		1.2	3.6	V		
V _{CC(B)}	supply voltage B		1.65	5.5	V		
VI	input voltage		0	1.2 3.6 1.65 5.5			
Vo	output voltage	Power-down or 3-state mode; $V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$					
		A port	0	3.6	V		
		B port	0	5.5	V		
T _{amb}	ambient temperature		-40	+125	°C		
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$	-	40	ns/V		

[1] The A and B sides of an unused I/O pair must be held in the same state, both at V_{CCI} or both at GND.

[2] $V_{CC(A)}$ must be less than or equal to $V_{CC(B)}$.

10. Static characteristics

Table 7. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{ОН}	HIGH-level output voltage	A port; $V_{CC(A)}$ = 1.2 V; I_0 = -20 μ A		-	1.1	-	V
V _{OL}	LOW-level output voltage	A port; $V_{CC(A)}$ = 1.2 V; I_0 = 20 μ A		-	0.09	-	V
I _I	input leakage current	OE input; V _I = 0 V to 3.6 V; V _{CC(A)} = 1.2 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V		-	-	±1	μA
I _{OZ}	OFF-state output current	A or B port; $V_O = 0$ V to V_{CCO} ; $V_{CC(A)} = 1.2$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V	[1]	-	-	±1	μA
I _{OFF}	power-off leakage current	A port; V _I or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0 V to 5.5 V		-	-	±1	μA
		B port; V _I or V _O = 0 V to 5.5 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0 V to 3.6 V		-	-	±1	μA
I _{CC}	supply current	$V_I = 0 V \text{ or } V_{CCI}; I_O = 0 A$	[2]				
		$I_{CC(A)}$; $V_{CC(A)}$ = 1.2 V; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	0.05	-	μA
		$I_{CC(B)}$; $V_{CC(A)} = 1.2$ V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	3.3	-	μΑ
		$I_{CC(A)} + I_{CC(B)}$; $V_{CC(A)} = 1.2$ V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	3.5	-	μΑ
CI	input capacitance	OE input; $V_{CC(A)}$ = 1.2 V to 3.6 V; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	1.0	-	pF
C _{I/O}	input/output	A port; $V_{CC(A)}$ = 1.2 V to 3.6 V; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	4.0	-	pF
	capacitance	B port; $V_{CC(A)} = 1.2$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	7.5	-	pF

[1] V_{CCO} is the supply voltage associated with the output.

[2] V_{CCI} is the supply voltage associated with the input.

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Table 8.Typical supply current

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $T_{amb} = 25$ °C.

V _{CC(A)}	V _{CC(B)}										
	1.8	3 V	2.	2.5 V		3.3 V		5.0 V			
	I _{CC(A)}	I _{CC(B)}									
1.2 V	10	10	10	10	10	20	10	1050	nA		
1.5 V	10	10	10	10	10	10	10	650	nA		
1.8 V	10	10	10	10	10	10	10	350	nA		
2.5 V	-	-	10	10	10	10	10	40	nA		
3.3 V	-	-	-	-	10	10	10	10	nA		

Table 9. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		–40 °C to	o +85 ℃	–40 °C to	+125 °C	Unit
				Min	Max	Min	Max	
V_{IH}	HIGH-level	A or B port and OE input	[1]					
	input voltage	$V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		0.65V _{CCI}	-	0.65V _{CCI}	-	V
V _{IL}	LOW-level	A or B port and OE input	[1]					
	input voltage	$V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	0.35V _{CCI}	-	0.35V _{CCI}	V
V _{OH}	HIGH-level	$I_{O} = -20 \ \mu A$	[2]					
	output voltage	A port; $V_{CC(A)} = 1.4$ V to 3.6 V		$V_{CCO}-0.4$	-	$V_{CCO}-0.4$	-	V
		B port; $V_{CC(B)}$ = 1.65 V to 5.5 V		$V_{CCO}-0.4$	-	$V_{CCO}-0.4$	-	V
V _{OL}	LOW-level	I _O = 20 μA	[2]					
	output voltage	A port; $V_{CC(A)} = 1.4$ V to 3.6 V		-	0.4	-	0.4	V
		B port; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	0.4	-	0.4	V
I	input leakage current	$\begin{array}{l} \text{OE input; V}_{I} = 0 \ \text{V to } 3.6 \ \text{V;} \\ \text{V}_{\text{CC}(A)} = 1.2 \ \text{V to } 3.6 \ \text{V;} \\ \text{V}_{\text{CC}(B)} = 1.65 \ \text{V to } 5.5 \ \text{V} \end{array}$		-	±2	-	±5	μΑ
I _{OZ}	OFF-state output current	A or B port; $V_0 = 0$ V or V_{CCO} ; $V_{CC(A)} = 1.2$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V	[2]	-	±2	-	±10	μA
I _{OFF}	power-off leakage	A port; V _I or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0 V to 5.5 V		-	±2	-	±10	μΑ
	current	B port; V _I or V _O = 0 V to 5.5 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0 V to 3.6 V		-	±2	-	±10	μA

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Symbol	Parameter	Conditions	–40 °C t	to +85 ℃	-40 °C to	o +125 °C	Unit
		-	Min	Max	Min	Max	_
I _{CC}	supply current	$V_{I} = 0 V \text{ or } V_{CCI}; I_{O} = 0 A$ [1]					
		I _{CC(A)}					
		OE = LOW; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	3	-	15	μA
		OE = HIGH; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	3	-	20	μA
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	-	2	-	15	μΑ
		$V_{CC(A)} = 0 V; V_{CC(B)} = 5.5 V$	-	-2	-	-15	μA
		I _{CC(B)}					
		OE = LOW; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	5	-	15	μA
		OE = HIGH; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V	-	5	-	20	μA
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	-	-2	-	-15	μA
		$V_{CC(A)} = 0 V; V_{CC(B)} = 5.5 V$	-	2	-	15	μΑ
		$I_{CC(A)} + I_{CC(B)}$					
		$V_{CC(A)} = 1.4 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$	-	8	-	40	μΑ

Table 9. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

[1] V_{CCI} is the supply voltage associated with the input.

[2] V_{CCO} is the supply voltage associated with the output.

11. Dynamic characteristics

 Table 10.
 Typical dynamic characteristics for temperature 25 °C^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for waveforms see Figure 6 and Figure 7.

Symbol	Parameter	Conditions			Unit			
				1.8 V	2.5 V	3.3 V	5.0 V	
$V_{CC(A)} = 1$	1.2 V; T _{amb} = 25 °C							
t _{pd}	propagation delay	A to B		5.9	4.8	4.4	4.2	ns
		B to A		5.6	4.8	4.5	4.4	ns
t _{en}	enable time	OE to A, B		0.5	0.5	0.5	0.5	μS
t _{dis}	disable time	OE to A; no external load	[2]	6.9	6.9	6.9	6.9	ns
		OE to B; no external load	[2]	9.5	8.6	8.5	8.0	ns
		OE to A		81	69	83	68	ns
		OE to B		81	69	83	68	ns
t _t	transition time	A port		4.0	4.0	4.1	4.1	ns
		B port		2.6	2.0	1.7	1.4	ns

Symbol	Parameter	Conditions		V _{CC(B)}						
			_	1.8 V	2.5 V	3.3 V	5.0 V			
t _{sk(o)}	output skew time	between channels	<u>[3]</u>	0.2	0.2	0.2	0.2	ns		
t _W	pulse width	data inputs		15	13	13	13	ns		
f _{data}	data rate			70	80	80	80	Mbps		

Table 10. Typical dynamic characteristics for temperature 25 °C^[1] ...continued

11-11---d to CND (ground 0.1/1) for tot oirquit and Figure 9; for ways for

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

ten is the same as tPZL and tPZH.

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

 t_{t} is the same as t_{THL} and t_{TLH}

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

Table 11. Dynamic characteristics for temperature range –40 °C to +85 °C^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7.

Symbol	Parameter	Conditions					Vcc	С(В)				Unit
				1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V :	± 0.5 V	
				Min	Max	Min	Max	Min	Max	Min	Max	
V _{CC(A)} =	1.5 V ± 0.1 V											
t _{pd}	propagation	A to B		1.4	12.9	1.2	10.1	1.1	10.0	0.8	9.9	ns
	delay	B to A		0.9	14.2	0.7	12.0	0.4	11.7	0.3	13.7	ns
t _{en}	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μS
t _{dis}	disable time	OE to A; no external load	[2]	1.0	11.9	1.0	11.9	1.0	11.9	1.0	11.9	ns
		OE to B; no external load	[2]	1.0	16.9	1.0	15.2	1.0	14.1	1.0	13.8	ns
		OE to A		-	320	-	260	-	260	-	280	ns
	OE to B		-	200	-	200	-	200	-	200	ns	
t _t transition time		A port		0.9	5.1	0.9	5.1	0.9	5.1	0.9	5.1	ns
	time	B port		0.9	4.7	0.6	3.2	0.5	2.5	0.4	2.7	ns
t _{sk(o)}	output skew time	between channels	<u>[3]</u>	-	0.5	-	0.5	-	0.5	-	0.5	ns
t _W	pulse width	data inputs		25	-	25	-	25	-	25	-	ns
f _{data}	data rate			-	40	-	40	-	40	-	40	Mbps
V _{CC(A)} =	1.8 V ± 0.15 V											
t _{pd}	propagation	A to B		1.6	11.0	1.4	7.7	1.3	6.8	1.2	6.5	ns
	delay	B to A		1.5	12.0	1.3	8.4	1.0	7.6	0.9	7.1	ns
t _{en}	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μS
t _{dis}	disable time	OE to A; no external load	[2]	1.0	11.0	1.0	11.0	1.0	11.0	1.0	11.0	ns
		OE to B; no external load	[2]	1.0	15.4	1.0	13.5	1.0	12.4	1.0	12.1	ns
		OE to A		-	260	-	230	-	230	-	230	ns
		OE to B		-	200	-	200	-	200	-	200	ns
t _t	transition	A port		0.8	4.1	0.8	4.1	0.8	4.1	0.8	4.1	ns
	time	B port		0.9	4.7	0.6	3.2	0.5	2.5	0.4	2.7	ns

Symbol	Parameter	Conditions					Vcc	:(B)				Unit
				1.8 V ±	: 0.15 V	2.5 V :		1	± 0.3 V	5.0 V :	± 0.5 V	-
				Min	Max	Min	Max	Min	Max	Min	Max	-
sk(o)	output skew time	between channels	<u>[3]</u>	-	0.5	-	0.5	-	0.5	-	0.5	ns
t _W	pulse width	data inputs		20	-	17	-	17	-	17	-	ns
f _{data}	data rate			-	49	-	60	-	60	-	60	Mbps
$V_{CC(A)} =$	2.5 V ± 0.2 V											
t _{pd}	propagation	A to B		-	-	1.1	6.3	1.0	5.2	0.9	4.7	ns
	delay	B to A		-	-	1.2	6.6	1.1	5.1	0.9	4.4	ns
t _{en}	enable time	OE to A, B		-	-	-	1.0	-	1.0	-	1.0	μS
t _{dis}	disable time	OE to A; no external load	[2]	-	-	1.0	9.2	1.0	9.2	1.0	9.2	ns
		OE to B; no external load	[2]	-	-	1.0	11.9	1.0	10.7	1.0	10.2	ns
		OE to A		-	-	-	200	-	200	-	200	ns
		OE to B		-	-	-	200	-	200	-	200	ns
t	transition	A port		-	-	0.7	3.0	0.7	3.0	0.7	3.0	ns
	time	B port		-	-	0.7	3.2	0.5	2.5	0.4	2.7	ns
sk(o)	output skew time	between channels	<u>[3]</u>	-	-	-	0.5	-	0.5	-	0.5	ns
t _W	pulse width	data inputs		-	-	12	-	10	-	10	-	ns
f _{data}	data rate			-	-	-	85	-	100	-	100	Mbp
$V_{CC(A)} =$	3.3 V ± 0.3 V											
t _{pd}	propagation	A to B		-	-	-	-	0.9	4.7	0.8	4.0	ns
	delay	B to A		-	-	-	-	1.0	4.9	0.9	3.8	ns
t _{en}	enable time	OE to A, B		-	-	-	-	-	1.0	-	1.0	μS
dis	disable time	OE to A; no external load	[2]	-	-	-	-	1.0	9.2	1.0	9.2	ns
		OE to B; no external load	[2]	-	-	-	-	1.0	10.1	1.0	9.6	ns
		OE to A		-	-	-	-	-	260	-	260	ns
		OE to B		-	-	-	-	-	200	-	200	ns
t	transition	A port		-	-	-	-	0.7	2.5	0.7	2.5	ns
	time	B port		-	-	-	-	0.5	2.5	0.4	2.7	ns
sk(o)	output skew time	between channels	<u>[3]</u>	-	-	-	-	-	0.5	-	0.5	ns
t _W	pulse width	data inputs		-	-	-	-	10	-	10	-	ns
f _{data}	data rate			-	-	-	-	-	100	-	100	Mbp

Dynamic characteristics for temperature range -40 °C to +85 °C[1] ... continued Table 11.

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $t_{en} \mbox{ is the same as } t_{PZL} \mbox{ and } t_{PZH}.$

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

 $t_{t}\xspace$ is the same as $t_{THL}\xspace$ and $t_{TLH}.$

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

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Symbol	Parameter	Conditions					Vcc					Unit
				1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V :	± 0.5 V	
				Min	Max	Min	Max	Min	Max	Min	Max	
V _{CC(A)} =	1.5 V ± 0.1 V											
t _{pd}	propagation	A to B		1.4	15.9	1.2	13.1	1.1	13.0	0.8	12.9	ns
	delay	B to A		0.9	17.2	0.7	15.0	0.4	14.7	0.3	16.7	ns
t _{en}	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μS
t _{dis}	disable time	OE to A; no external load	[2]	1.0	12.5	1.0	12.5	1.0	12.5	1.0	12.5	ns
		OE to B; no external load	[2]	1.0	18.1	1.0	16.2	1.0	14.9	1.0	14.6	ns
		OE to A		-	340	-	280	-	280	-	300	ns
		OE to B		-	220	-	220	-	220	-	220	ns
t	transition	A port		0.9	7.1	0.9	7.1	0.9	7.1	0.9	7.1	ns
	time	B port		0.9	6.5	0.6	5.2	0.5	4.8	0.4	4.7	ns
sk(o)	output skew time	between channels	<u>[3]</u>	-	0.5	-	0.5	-	0.5	-	0.5	ns
tw	pulse width	data inputs		25	-	25	-	25	-	25	-	ns
data	data rate			-	40	-	40	-	40	-	40	Mb
/ _{CC(A)} =	1.8 V ± 0.15 V											
pd	propagation	A to B		1.6	14.0	1.4	10.7	1.3	9.8	1.2	9.5	ns
	delay	B to A		1.5	15.0	1.3	11.4	1.0	10.6	0.9	10.1	ns
en	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μS
t _{dis} disa		OE to A; no external load	[2]	1.0	11.5	1.0	11.5	1.0	11.5	1.0	11.5	ns
		OE to B; no external load	[2]	1.0	16.5	1.0	14.5	1.0	13.3	1.0	12.7	ns
		OE to A		-	280	-	250	-	250	-	250	ns
		OE to B		-	220	-	220	-	220	-	220	ns
t	transition	A port		0.8	6.2	0.8	6.1	0.8	6.1	0.8	6.1	ns
	time	B port		0.9	5.8	0.6	5.2	0.5	4.8	0.4	4.7	ns
sk(o)	output skew time	between channels	<u>[3]</u>	-	0.5	-	0.5	-	0.5	-	0.5	ns
W	pulse width	data inputs		22	-	19	-	19	-	19	-	ns
data	data rate			-	45	-	55	-	55	-	55	Mb
/ _{CC(A)} =	2.5 V ± 0.2 V											
pd	propagation	A to B		-	-	1.1	9.3	1.0	8.2	0.9	7.7	ns
	delay	B to A		-	-	1.2	9.6	1.1	8.1	0.9	7.4	ns
en	enable time	OE to A, B		-	-	-	1.0	-	1.0	-	1.0	μS
dis	disable time	OE to A; no external load	[2]	-	-	1.0	9.6	1.0	9.6	1.0	9.6	ns
		OE to B; no external load	[2]	-	-	1.0	12.6	1.0	11.4	1.0	10.8	ns
		OE to A		-	-	-	220	-	220	-	220	ns
		OE to B		-	-	-	220	-	220	-	220	ns
t	transition	A port		-	-	0.7	5.0	0.7	5.0	0.7	5.0	ns
	time	B port		-	-	0.7	4.6	0.5	4.8	0.4	4.7	ns

Table 12. Dynamic characteristics for temperature range –40 °C to +125 °C[1]

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Symbol	Parameter	Conditions					Vcc	C(B)				Unit
				1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V =	± 0.5 V	
				Min	Max	Min	Max	Min	Max	Min	Max	
t _{sk(o)}	output skew time	between channels	<u>[3]</u>	-	-	-	0.5	-	0.5	-	0.5	ns
t _W	pulse width	data inputs;		-	-	14	-	13	-	10	-	ns
f _{data}	data rate			-	-	-	75	-	80	-	100	Mbps
V _{CC(A)} =	3.3 V ± 0.3 V											
t _{pd}	propagation	A to B		-	-	-	-	0.9	7.7	0.8	7.0	ns
	delay	B to A		-	-	-	-	1.0	7.9	0.9	6.8	ns
t _{en}	enable time	OE to A, B		-	-	-	-	-	1.0	-	1.0	μS
t _{dis}	disable time	OE to A; no external load	[2]	-	-	-	-	1.0	9.5	1.0	9.5	ns
		OE to B; no external load	[2]	-	-	-	-	1.0	10.7	1.0	9.6	ns
		OE to A		-	-	-	-	-	280	-	280	ns
		OE to B		-	-	-	-	-	220	-	220	ns
t _t	transition	A port		-	-	-	-	0.7	4.5	0.7	4.5	ns
	time	B port		-	-	-	-	0.5	4.1	0.4	4.7	ns
t _{sk(o)}	output skew time	between channels	<u>[3]</u>	-	-	-	-	-	0.5	-	0.5	ns
t _W	pulse width	data inputs		-	-	-	-	10	-	10	-	ns
f _{data}	data rate			-	-	-	-	-	100	-	100	Mbps

Table 12. Dynamic characteristics for temperature range $-40 \degree$ C to $+125 \degree$ C^[1] ...continued Voltages are referenced to GND (ground = 0 V): for test circuit see Figure 8: for wave forms see Figure 6 and Figure 7

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $t_{en} \mbox{ is the same as } t_{PZL} \mbox{ and } t_{PZH}.$

 t_{dis} is the same as t_{PLZ} and t_{PHZ} . t_{t} is the same as t_{THL} and $t_{\text{TLH.}}$

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

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Symbol	Parameter	Conditions				V _{CC(A)}				Unit
			1.2 V	1.2 V	1.5 V	1.8 V	2.5 V	2.5 V	3.3 V	
			V _{CC(B)}							
			1.8 V	5.0 V	1.8 V	1.8 V	2.5 V	5.0 V	3.3 V to 5.0 V	
T _{amb} = 2	S ℃							1		
10	power	outputs enabled; $OE = V_{CC(A)}$								
	dissipation capacitance	A port: (direction A to B)	5	5	5	5	5	5	5	pF
		A port: (direction B to A)	8	8	8	8	8	8	8	pF
		B port: (direction A to B)	18	18	18	18	18	18	18	pF
		B port: (direction B to A)	13	16	12	12	12	12	13	pF
		outputs disabled; OE = GND								
		A port: (direction A to B)	0.12	0.12	0.04	0.05	0.08	0.08	0.07	pF
		A port: (direction B to A)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
		B port: (direction A to B)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
		B port: (direction B to A)	0.07	0.09	0.07	0.07	0.05	0.09	0.09	pF

Table 13. Typical power dissipation capacitance Voltages are referenced to GND (ground = 0 V).[1][2]

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

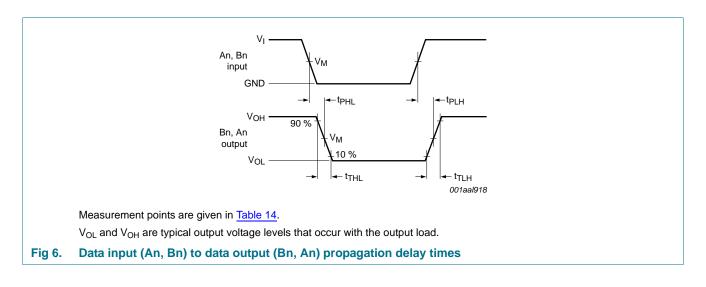
 C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12. Waveforms



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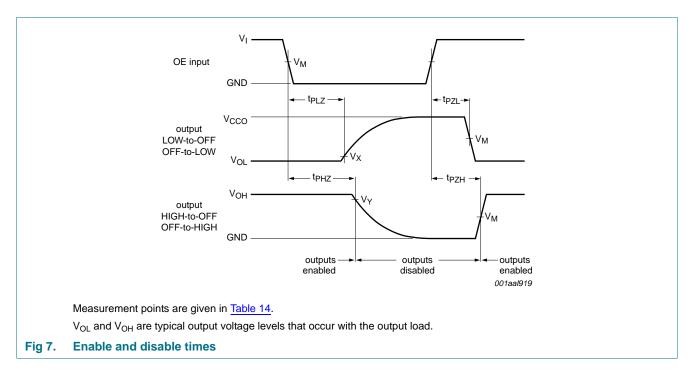


Table 14. Measurement points^[1]

Tuble 14. Measuren				
Supply voltage	Input	Output		
V _{cco}	V _M	V _M	V _X	V _Y
1.2 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.1 V	V _{OH} – 0.1 V
$1.5~\text{V}\pm0.1~\text{V}$	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.1 V	V _{OH} – 0.1 V
$1.8 \text{ V} \pm 0.15 \text{ V}$	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.15 V	V _{OH} – 0.15 V
$2.5~\textrm{V}\pm0.2~\textrm{V}$	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.15 V	V _{OH} – 0.15 V
$3.3 \text{ V} \pm 0.3 \text{ V}$	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.3 V	V _{OH} – 0.3 V
$5.0~\text{V}\pm0.5~\text{V}$	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.3 V	V _{OH} – 0.3 V

[1] V_{CCI} is the supply voltage associated with the input and V_{CCO} is the supply voltage associated with the output.

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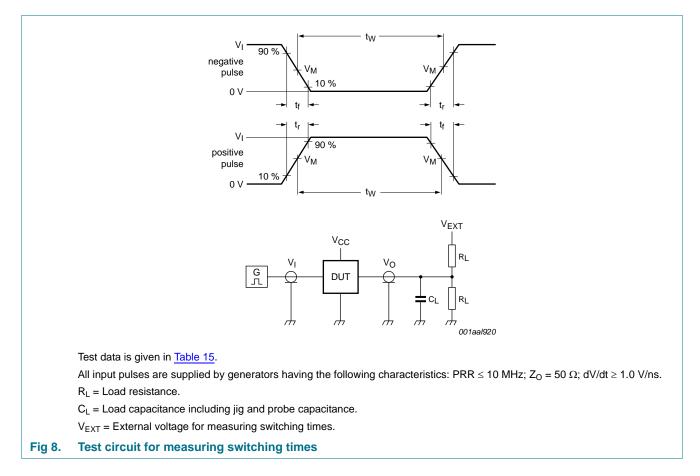


Table 15. Test data

Supply voltage		Input		Load		V _{EXT}		
V _{CC(A)}	V _{CC(B)}	VI <mark>[1]</mark>	∆t/∆V	CL	R _L [2]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ} [3]
1.2 V to 3.6 V	1.65 V to 5.5 V	V _{CCI}	\leq 1.0 ns/V	15 pF	50 kΩ, 1 MΩ	open	open	2V _{CCO}

[1] V_{CCI} is the supply voltage associated with the input.

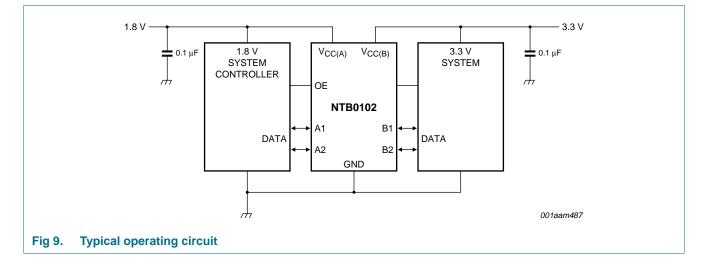
[2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements, $R_L = 1 M\Omega$; for measuring enable and disable times, $R_L = 50 k\Omega$.

[3] V_{CCO} is the supply voltage associated with the output.

13. Application information

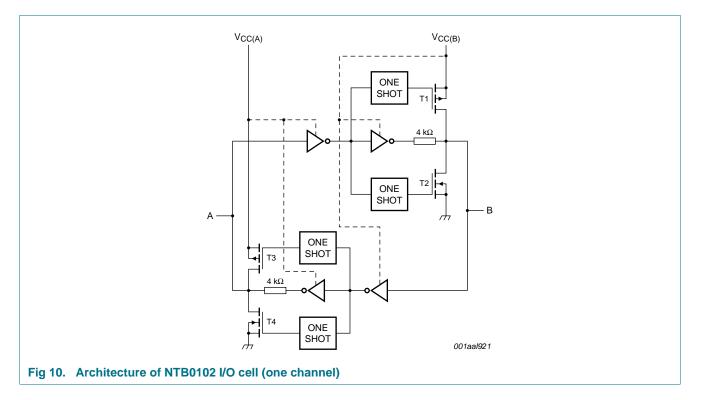
13.1 Applications

Voltage level-translation applications. The NTB0102 can be used to interface between devices or systems operating at different supply voltages. See Figure 9 for a typical operating circuit using the NTB0102.



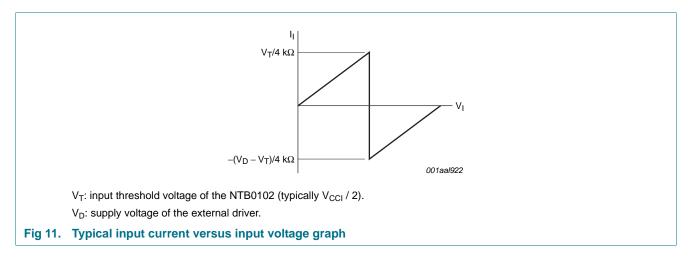
13.2 Architecture

The architecture of the NTB0102 is shown in Figure 10. The device does not require an extra input signal to control the direction of data flow from A to B or from B to A. In a static state, the output drivers of the NTB0102 can maintain a defined output level, but the output architecture is designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing in the opposite direction. The output of one-shot circuits detect rising or falling edges on the A or B ports. During a rising edge, the one-shot circuits turn on the PMOS transistors (T1, T3) for a short duration, accelerating the LOW-to-HIGH transition. Similarly, during a falling edge, the one-shot circuits turn on the NMOS transistors (T2, T4) for a short duration, accelerating the HIGH-to-LOW transition. During output transitions the typical output impedance is 70 Ω at V_{CCO} = 1.2 V to 1.8 V, 50 Ω at V_{CCO} = 1.8 V to 3.3 V and 40 Ω at V_{CCO} = 3.3 V to 5.0 V.



13.3 Input driver requirements

For correct operation, the device driving the data I/Os of the NTB0102 must have a minimum drive capability of ± 2 mA See <u>Figure 11</u> for a plot of typical input current versus input voltage.



13.4 Power-up

During operation $V_{CC(A)}$ must never be higher than $V_{CC(B)}$, however during power-up $V_{CC(A)} \ge V_{CC(B)}$ does not damage the device, so either power supply can be ramped up first. There is no special power-up sequencing required. The NTB0102 includes circuitry that disables all output ports when either $V_{CC(A)}$ or $V_{CC(B)}$ is switched off.

13.5 Enable and disable

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state. The disable time (t_{dis} with no external load) indicates the delay between when OE goes LOW and when outputs actually become disabled. The enable time (t_{en}) indicates the amount of time the user must allow for one one-shot circuitry to become operational after OE is taken HIGH. To ensure the high-impedance OFF-state during power-up or power-down, pin OE should be tied to GND through a pull-down resistor, the minimum value of the resistor is determined by the current-sourcing capability of the driver.

13.6 Pull-up or pull-down resistors on I/O lines

As mentioned previously the NTB0102 is designed with low static drive strength to drive capacitive loads of up to 70 pF. To avoid output contention issues, any pull-up or pull-down resistors used must be above 50 k Ω . For this reason the NTB0102 is not recommended for use in open drain driver applications such as 1-Wire or I²C-bus. For these applications, the NTS0102 level translator is recommended.

14. Package outline

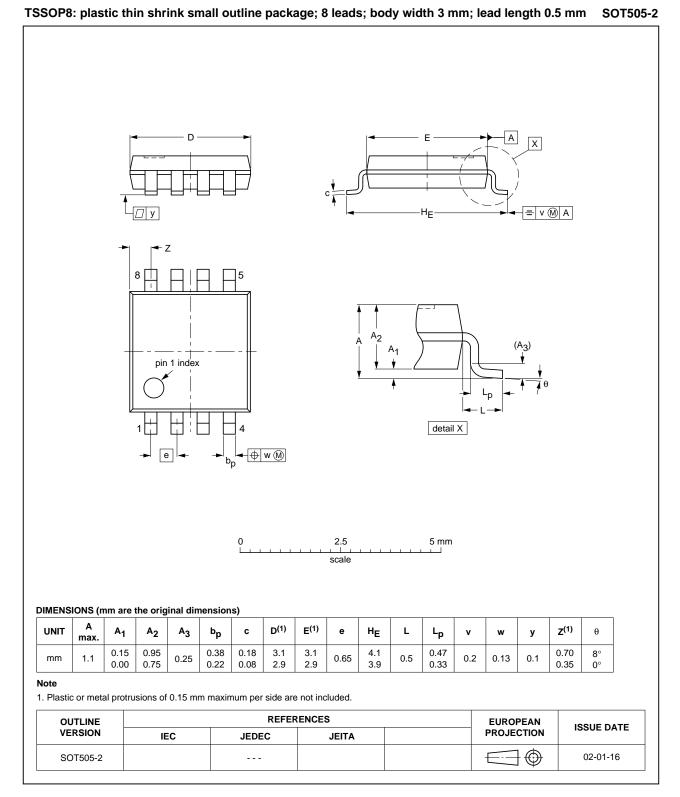


Fig 12. Package outline SOT505-2 (TSSOP8)

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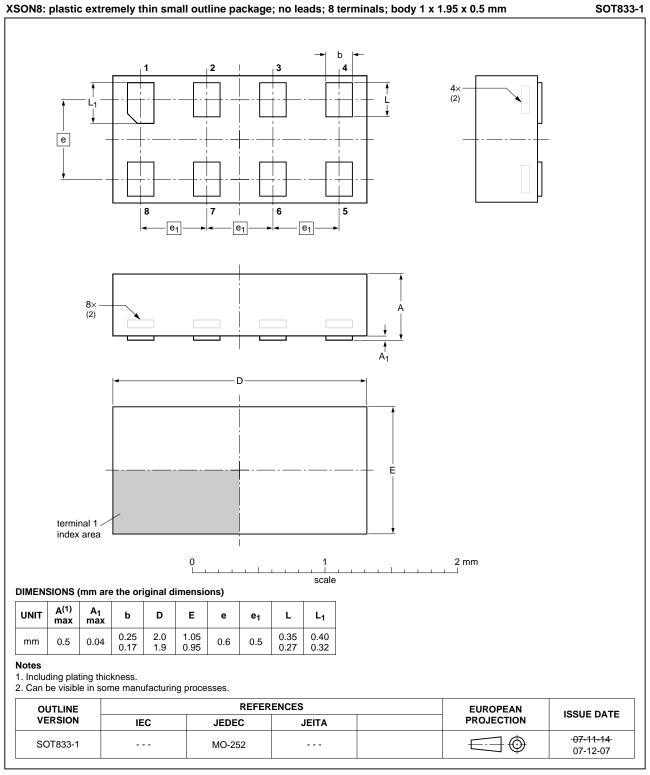
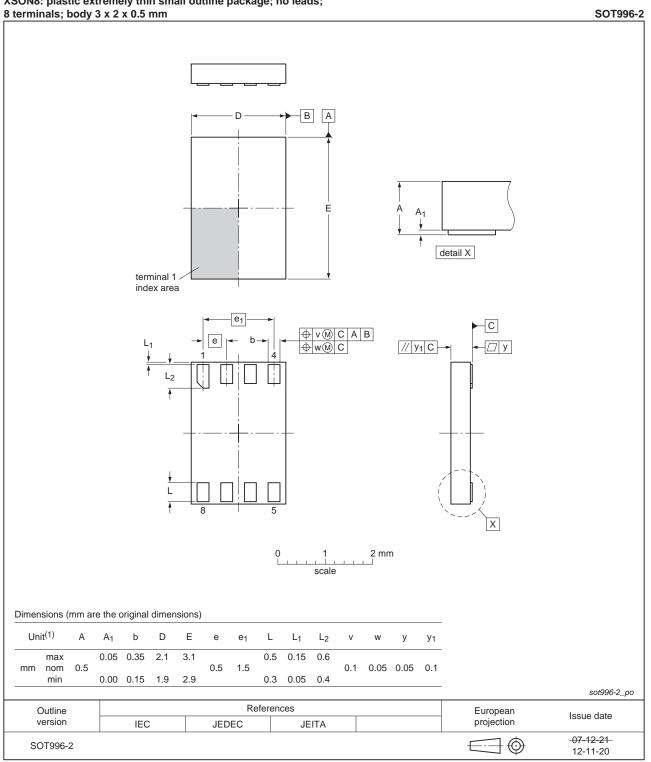


Fig 13. Package outline SOT833-1 (XSON8)

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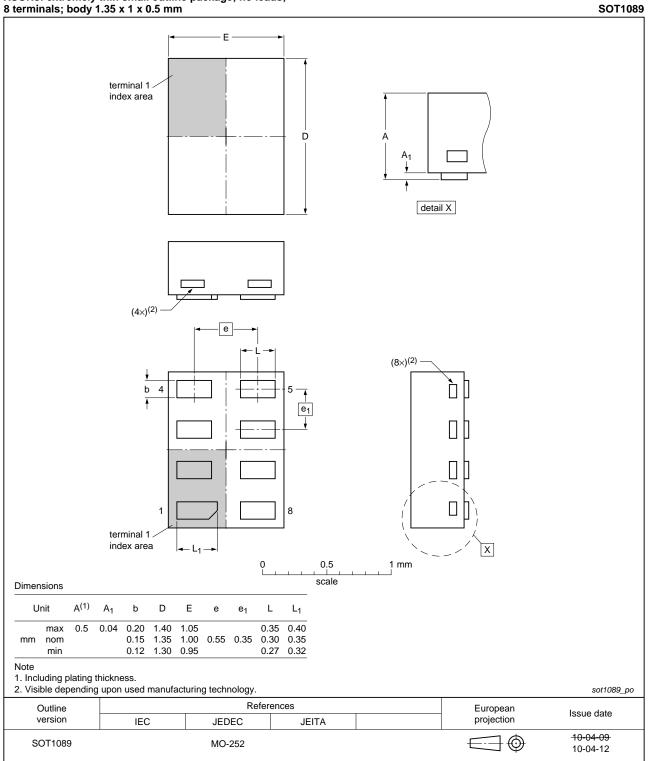


XSON8: plastic extremely thin small outline package; no leads;

Fig 14. Package outline SOT996-2 (XSON8)

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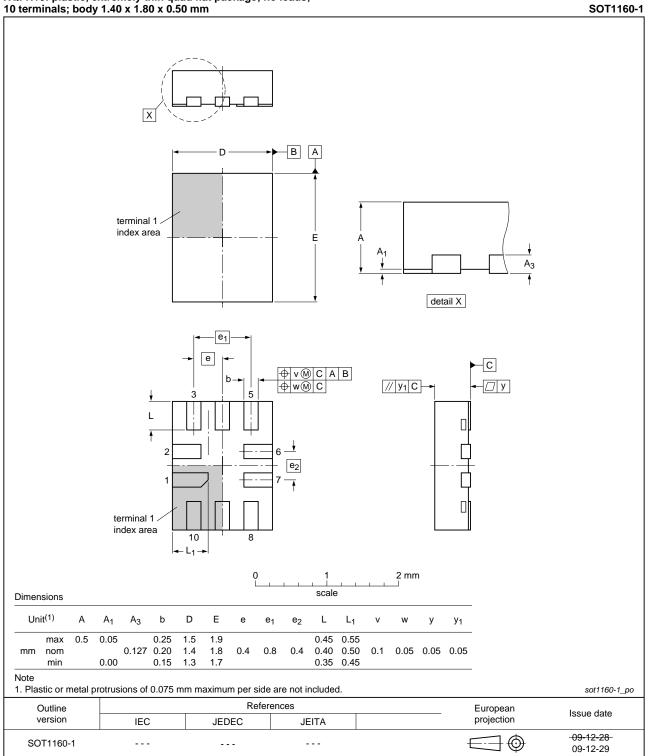


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig 15. Package outline SOT1089 (XSON8)

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XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 x 1.80 x 0.50 mm

Fig 16. Package outline SOT1160-1 (XQFN10)

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15. Abbreviations

Table 16.	Abbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
NMOS	N-type Metal Oxide Semiconductor
PMOS	P-type Metal Oxide Semiconductor
PRR	Pulse Repetition Rate

16. Revision history

Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NTB0102 v.4	20130123	Product data sheet	-	NTB0102 v.3
Modifications:	 For type nur 	nber NTB0102GD XSON8U h	as changed to XSON8	•
NTB0102 v.3	20111110	Product data sheet	-	NTB0102 v.2
Modifications:	 Legal pages 	updated.		
NTB0102 v.2	20110428	Product data sheet	-	NTB0102 v.1
NTB0102 v.1	20100922	Product data sheet	-	-

17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NTB0102

Dual supply translating transceiver; auto direction sensing; 3-state

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